

MOSFETs Silicon N-Channel MOS (DTMOSVI)

# TK065N65Z

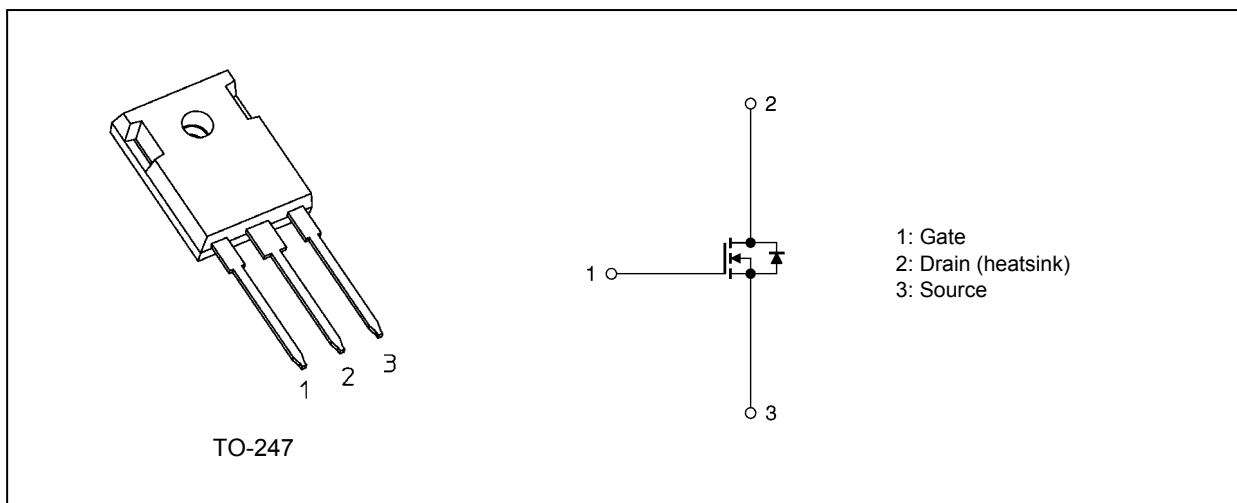
## 1. Applications

- Switching Power Supplies

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.054 \Omega$  (typ.)
- (2) High-speed switching properties with lower capacitance.
- (3) Enhancement mode:  $V_{th} = 3$  to  $4$  V ( $V_{DS} = 10$  V,  $I_D = 1.69$  mA)

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                | Symbol    | Rating     | Unit             |
|--------------------------------|-----------|------------|------------------|
| Drain-source voltage           | $V_{DSS}$ | 650        | V                |
| Gate-source voltage            | $V_{GSS}$ | $\pm 30$   |                  |
| Drain current (DC)             | $I_D$     | 38         | A                |
| Drain current (pulsed)         | $I_{DP}$  | 152        |                  |
| Power dissipation              | $P_D$     | 270        | W                |
| Single-pulse avalanche energy  | $E_{AS}$  | 569        | mJ               |
| Single-pulse avalanche current | $I_{AS}$  | 9.5        | A                |
| Reverse drain current (DC)     | $I_{DR}$  | 38         |                  |
| Reverse drain current (pulsed) | $I_{DRP}$ | 152        |                  |
| Channel temperature            | $T_{ch}$  | 150        | $^\circ\text{C}$ |
| Storage temperature            | $T_{stg}$ | -55 to 150 |                  |
| Mounting torque                | TOR       | 0.8        | N · m            |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

2019-03

## 5. Thermal Characteristics

| Characteristics                       | Symbol         | Max   | Unit |
|---------------------------------------|----------------|-------|------|
| Channel-to-case thermal resistance    | $R_{th(ch-c)}$ | 0.462 | °C/W |
| Channel-to-ambient thermal resistance | $R_{th(ch-a)}$ | 50    |      |

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2:  $V_{DD} = 90\text{ V}$ ,  $T_{ch} = 25\text{ °C}$  (initial),  $L = 11.2\text{ mH}$ ,  $I_{AS} = 9.5\text{ A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

## 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                | Symbol        | Test Condition                                  | Min | Typ.  | Max     | Unit          |
|--------------------------------|---------------|---|-----|-------|---------|---------------|
| Gate leakage current           | $I_{GSS}$     | $V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$ | —   | —     | $\pm 1$ | $\mu\text{A}$ |
| Drain cut-off current          | $I_{DSS}$     | $V_{DS} = 650\text{ V}, V_{GS} = 0\text{ V}$    | —   | —     | 2       |               |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$       | 650 | —     | —       | V             |
| Gate threshold voltage         | $V_{th}$      | $V_{DS} = 10\text{ V}, I_D = 1.69\text{ mA}$    | 3   | —     | 4       |               |
| Drain-source on-resistance     | $R_{DS(ON)}$  | $V_{GS} = 10\text{ V}, I_D = 19\text{ A}$       | —   | 0.054 | 0.065   | $\Omega$      |

### 6.2. Dynamic Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                | Symbol      | Test Condition   | Min | Typ. | Max | Unit          |
|--------------------------------|-------------|--|-----|------|-----|---------------|
| Input capacitance              | $C_{iss}$   | $V_{DS} = 300\text{ V}, V_{GS} = 0\text{ V}, f = 100\text{ kHz}$ | —   | 3650 | —   | $\mu\text{F}$ |
| Reverse transfer capacitance   | $C_{rss}$   |  | —   | 2.5  | —   |               |
| Output capacitance             | $C_{oss}$   |  | —   | 83   | —   |               |
| Effective output capacitance   | $C_{o(er)}$ | $V_{DS} = 0\text{ to }400\text{ V}, V_{GS} = 0\text{ V}$         | —   | 148  | —   | $\mu\text{F}$ |
| Gate resistance                | $r_g$       | $V_{DS} = \text{OPEN}, f = 1\text{ MHz}$                         | —   | 3    | —   | $\Omega$      |
| Switching time (rise time)     | $t_r$       | See Figure 6.2.1   | —   | 62   | —   | ns            |
| Switching time (turn-on time)  | $t_{on}$    |  | —   | 110  | —   |               |
| Switching time (fall time)     | $t_f$       |  | —   | 4.2  | —   |               |
| Switching time (turn-off time) | $t_{off}$   |  | —   | 130  | —   |               |
| MOSFET dv/dt ruggedness        | dv/dt       | $V_{DS} \leq V_{(BR)DSS}, I_D \leq 19\text{ A}$                  | 120 | —    | —   | V/ns          |

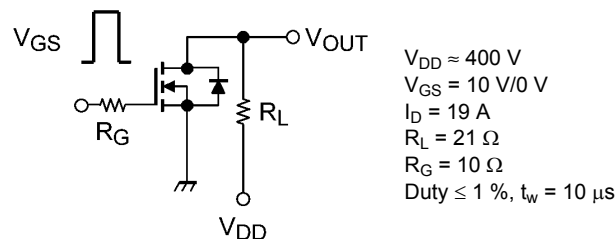


Fig. 6.2.1 Switching Time Test Circuit

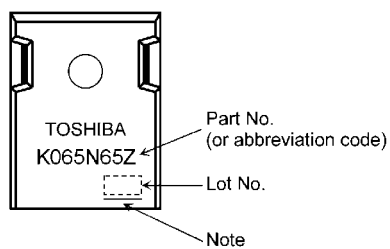
### 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics                                 | Symbol    | Test Condition   | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | $Q_g$     | $V_{DD} = 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 38\text{ A}$ | —   | 62   | —   | nC   |
| Gate-source charge 1                            | $Q_{gs1}$ |  | —   | 18   | —   |      |
| Gate-drain charge                               | $Q_{gd}$  |  | —   | 17   | —   |      |

### 6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics               | Symbol    | Test Condition   | Min | Typ. | Max  | Unit |
|-------------------------------|-----------|--|-----|------|------|------|
| Diode forward voltage         | $V_{DSF}$ | $I_{DR} = 38\text{ A}, V_{GS} = 0\text{ V}$  | —   | —    | -1.7 | V    |
| Reverse recovery time         | $t_{rr}$  | $V_{DD} = 400\text{ V}, I_{DR} = 19\text{ A}, V_{GS} = 0\text{ V}, -dI_{DR}/dt = 100\text{ A}/\mu\text{s}$ | —   | 350  | —    | ns   |
| Reverse recovery charge       | $Q_{rr}$  |  | —   | 6    | —    |      |
| Peak reverse recovery current | $I_{rr}$  |  | —   | 34   | —    |      |
| Diode dv/dt ruggedness        | dv/dt     | $V_{DD} \leq 400\text{ V}, I_{DR} \leq 19\text{ A}, V_{GS} = 0\text{ V}$                                   | 50  | —    | —    | V/ns |

## 7. Marking (Note)



**Fig. 7.1 Marking**

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

## 8. Characteristics Curves (Note)

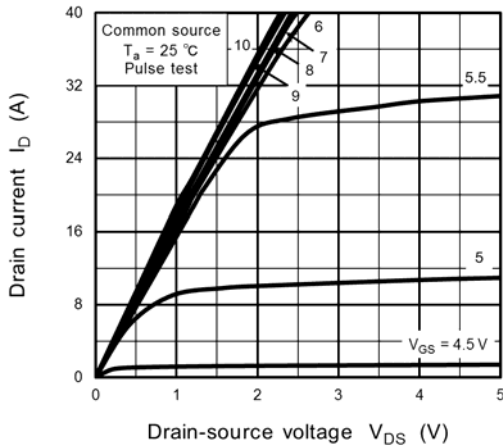


Fig. 8.1  $I_D - V_{DS}$

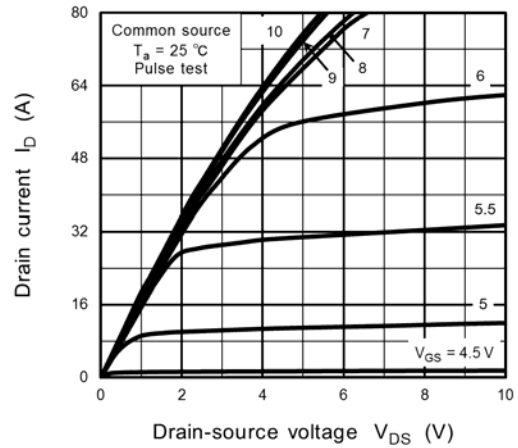


Fig. 8.2  $I_D - V_{DS}$

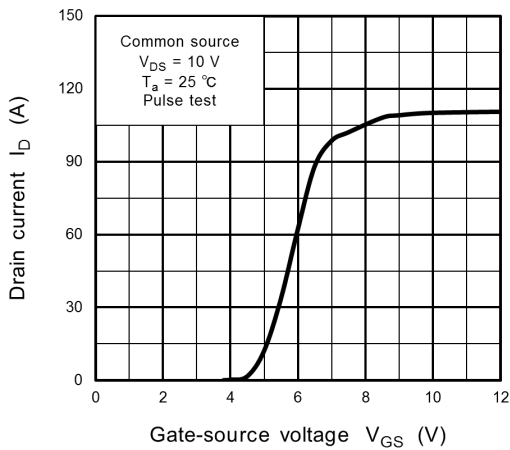


Fig. 8.3  $I_D - V_{GS}$

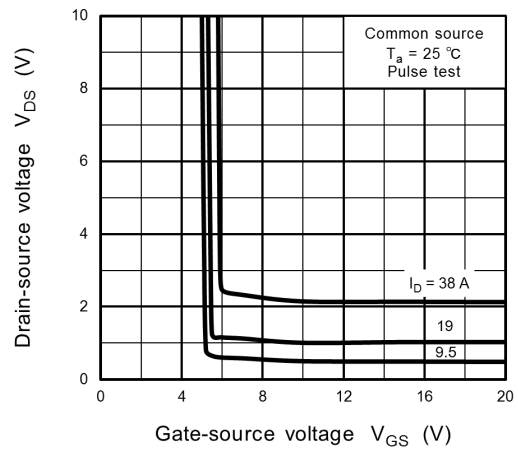


Fig. 8.4  $V_{DS} - V_{GS}$

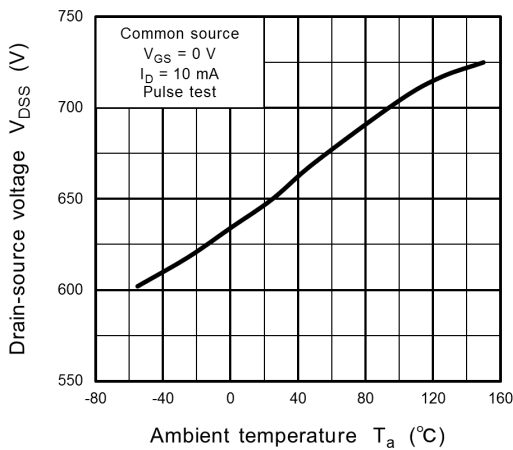


Fig. 8.5  $V_{DSS} - T_a$

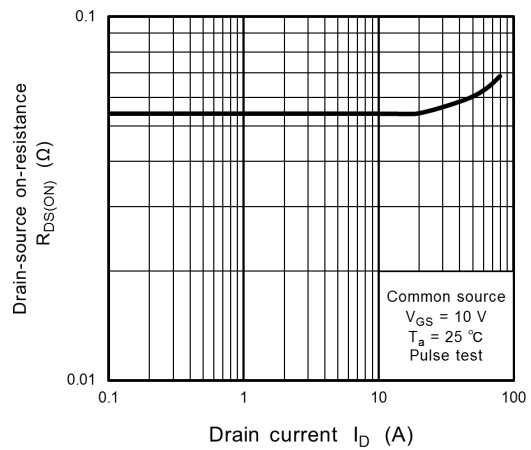


Fig. 8.6  $R_{DS(ON)} - I_D$

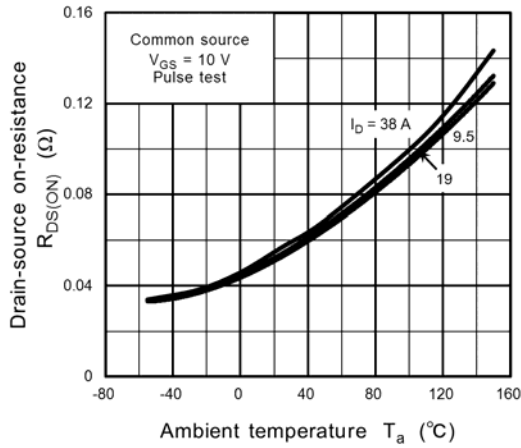


Fig. 8.7  $R_{DS(ON)} - T_a$

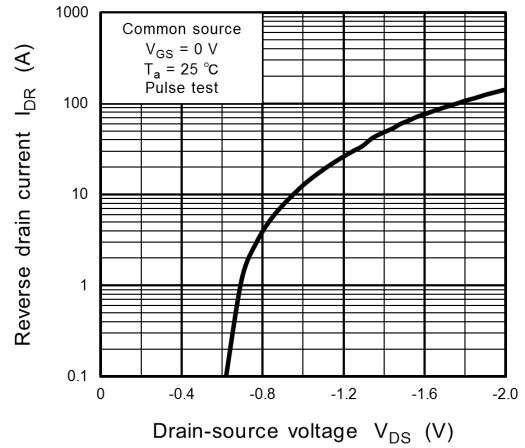


Fig. 8.8  $I_{DR} - V_{DS}$

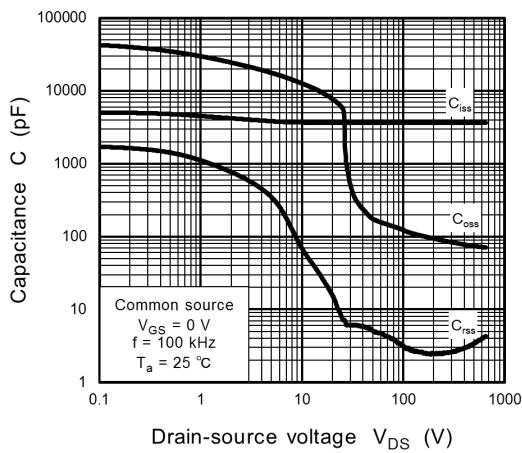


Fig. 8.9  $C - V_{DS}$

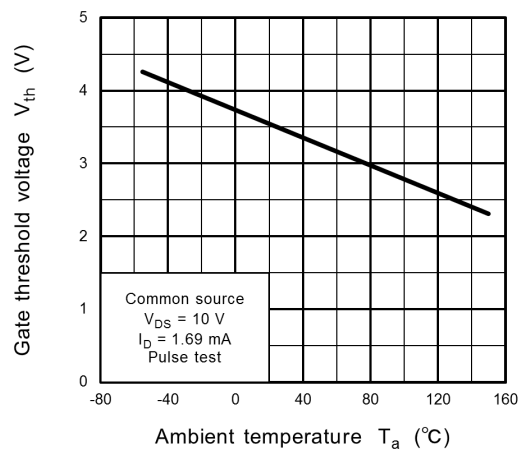


Fig. 8.10  $V_{th} - T_a$

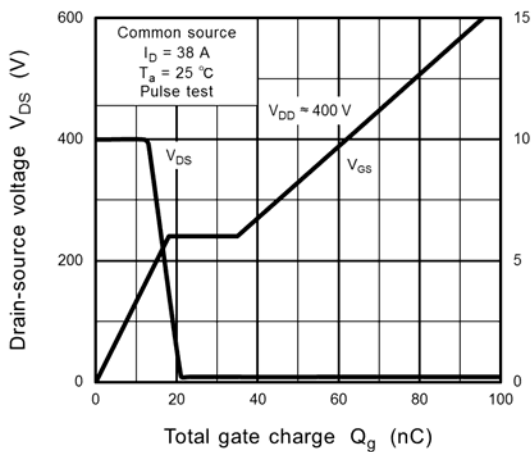


Fig. 8.11 Dynamic Input/Output Characteristics

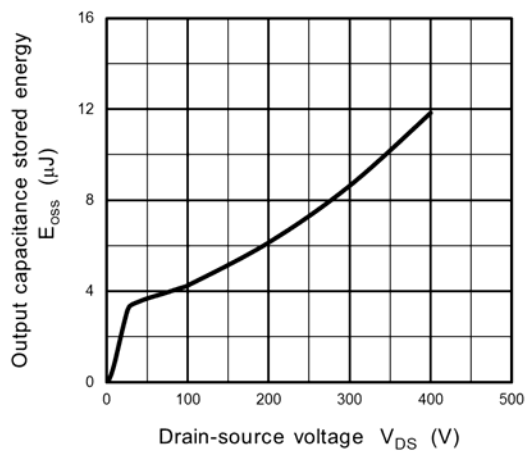
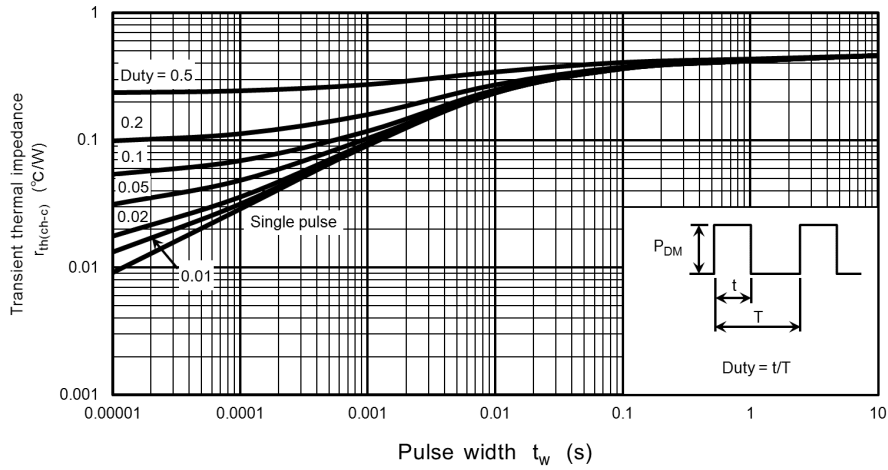
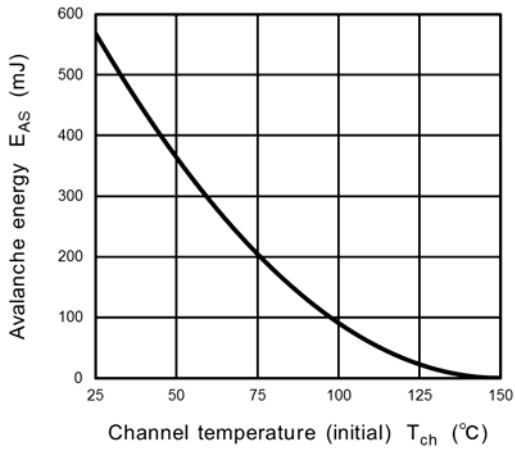


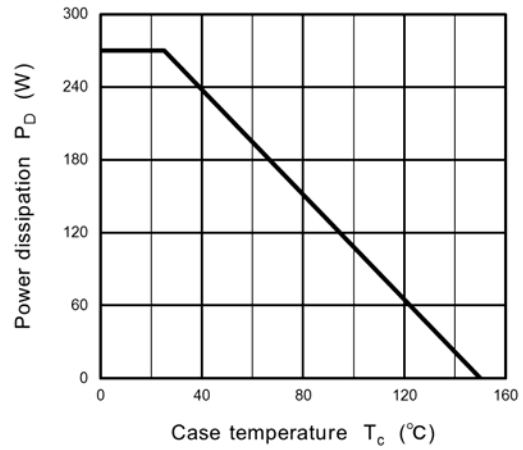
Fig. 8.12  $E_{oss} - V_{DS}$



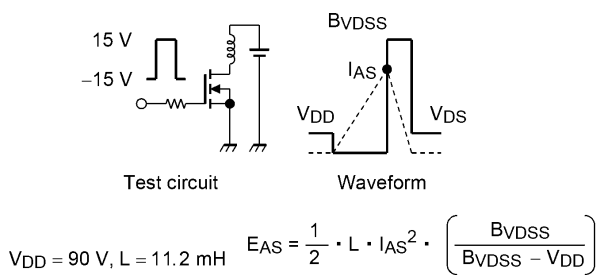
**Fig. 8.13  $r_{th} - t_w$**   
(Guaranteed Maximum)



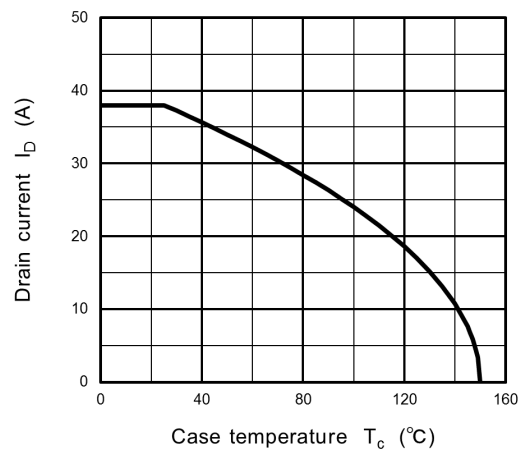
**Fig. 8.14  $E_{AS} - T_{ch}$**   
(Guaranteed Maximum)



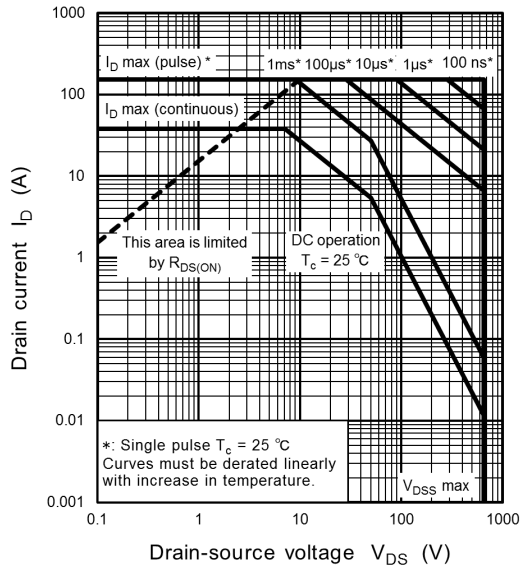
**Fig. 8.15  $P_D - T_c$**   
(Guaranteed Maximum)



**Fig. 8.16 Test Circuit/Waveform**



**Fig. 8.17  $I_D - T_c$**   
(Guaranteed Maximum)



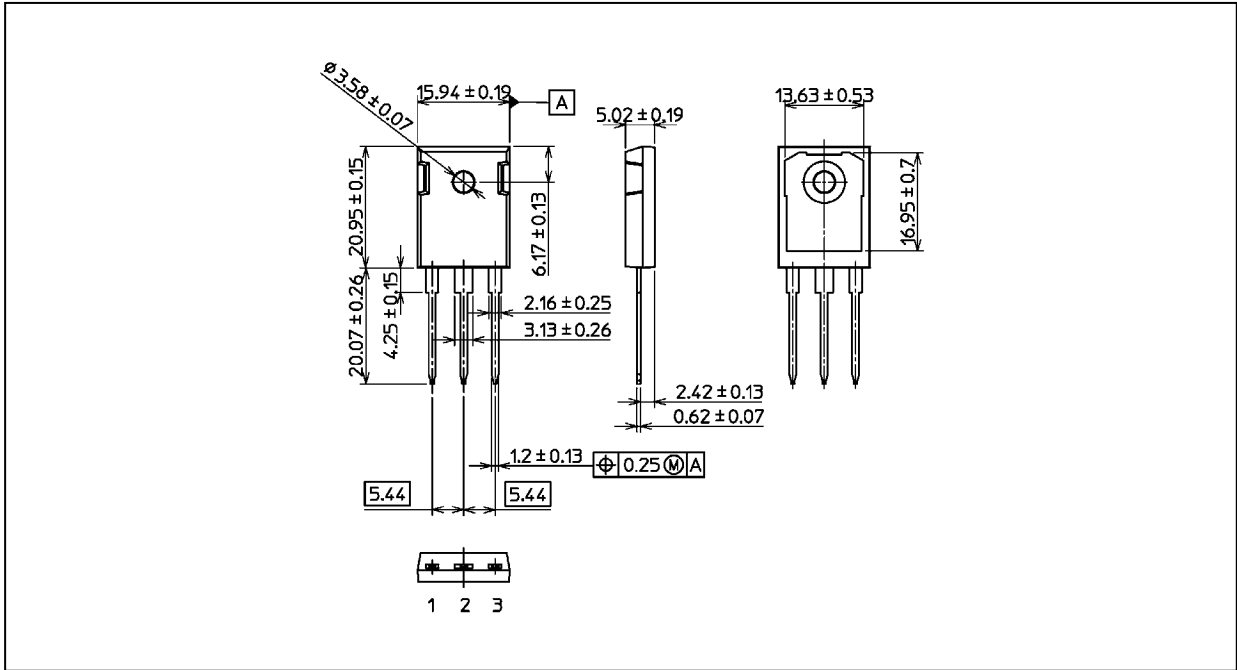
**Fig. 8.18 Safe Operating Area (Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## Package Dimensions

Unit: mm



Weight: 6.15 g (typ.)

| Package Name(s)  |
|------------------|
| JEITA: SC-65     |
| TOSHIBA: 2-16L1A |
| Nickname: TO-247 |

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